

Half-Bridge IPM for Small Appliance Motor Drive Applications



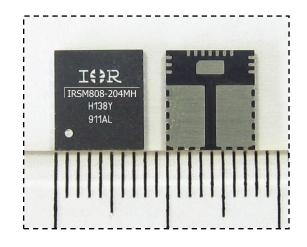
20A, 250V

Description

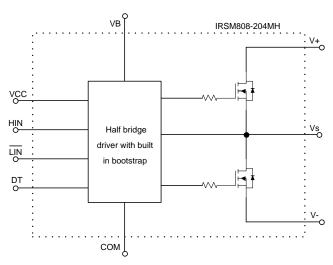
IRSM808-204MH is a 20A, 250V half-bridge module designed for advanced appliance motor drive applications such as energy efficient fans and pumps. IR's technology offers an extremely compact, high performance half-bridge topology in an isolated package. This advanced IPM offers a combination of IR's low R_{DS(on)} Trench MOSFET technology and the industry benchmark half-bridge high voltage, rugged driver in a small PQFN package. At only 8x9mm and featuring integrated bootstrap functionality, the compact footprint of this surface-mount package makes it suitable for applications that are space-constrained. IRSM808-204MH functions without a heat sink.

Features

- Integrated gate drivers and bootstrap functionality
- Suitable for sinusoidal modulation applications
- Low 0.15Ω R_{DS(on)} (max, 25°C) Trench MOSFET
- Under-voltage lockout for both channels
- Matched propagation delay for all channels
- Optimized dV/dt for loss and EMI trade offs
- 3.3V input logic compatible
- · Active high HIN and active low LIN
- Motor Power range 80-200W
- Isolation 1500V_{RMS} min
- ROHS compliant



Internal Electrical Schematic



Ordering Information

Orderable Part Number	Package Type	Form	Quantity	
IRSM808-204MH	PQFN 8x9mm	Tray	1300	
IRSM808-204MHTR	PQFN 8x9mm	Tape and Reel	2000	





Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the module may occur. These are not tested at manufacturing. All voltage parameters are absolute voltages referenced to V_{SS} unless otherwise stated in the table. The thermal resistance rating is measured under board mounted and still air conditions.

Symbol	Description	Min	Max	Unit
BV _{DSS}	MOSFET Blocking Voltage		250	V
Io	Output DC Current per MOSFET @ T _C =25°C (Note1)		20	Α
P _d	Power dissipation per MOSFET @ T _C =100°C (Note1)		38	W
T _J (MOSFET & IC)	Maximum Operating Junction Temperature		150	°C
TL	Lead temperature (soldering 30 seconds)		260	°C
Ts	Storage Temperature Range	-40	150	°C
V _B	High side floating supply voltage	-0.3	VS + 20	V
Vs	High side floating supply offset voltage	VB - 20	VB +0.3	V
Vcc	Low Side fixed supply voltage	-0.3	20	V
V _{IN}	Logic input voltage LIN, HIN	-0.3	VCC+0.3	V
V _{ISO}	Isolation voltage (1min) (Note2)		1500	V_{RMS}

Note1: Calculated based on maximum junction temperature. Bond wires current limit is 8A.

Note2: Characterized, not tested at manufacturing

Reccomended Operating Conditions

Symbol	Description	Min	Тур	Max	Units	Conditions
V ⁺	Positive DC Bus Input Voltage			200	V	
V _{S1,2,3}	High Side Floating Supply Offset Voltage	(Note 3)		200	V	
V _{B1,2,3}	High Side Floating Supply Voltage	V _S +12		V _S +20	V	
V _{CC}	Low Side and Logic Supply Voltage	13.5		16.5	V	
V _{IN}	Logic Input Voltage	СОМ		Vcc	V	
Fp	PWM Carrier Frequency			20	kHz	

For proper operation the module should be used within the recommended conditions. All voltages are absolute referenced to COM. The V_S offset is tested with all supplies biased at 15V differential.

Note 3: Logic operational for V_s from COM-8V to COM+250V. Logic state held for V_s from COM-8V to COM-V_{BS}.





Static Electrical Characteristics

 $V_{BIAS} \ (V_{CC}, \ V_{BS}) = 15 V, \ T_J = 25^{o}C, \ unless \ otherwise \ specified. \ The \ V_{IN}, \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ COM \ and \ I_{IN} \ parameters \ are \ referenced \ to \ I_{IN} \ parameters \ are \ referenced \ to \ I_{IN} \ parameters \ parameter$

Symbol	Description	Min	Тур	Max	Units	Conditions
BV _{DSS}	Drain-to-Source Breakdown Voltage	250			V	T _J =25°C, I _{LK} =250μA
I _{LKH}	Leakage Current of High Side FET's in Parallel		15		μΑ	T _J =25°C, V _{DS} =250V
I _{LKL}	Leakage Current of Low Side FET's in Parallel Plus Gate Drive IC		20		μΑ	T _J =25°C, V _{DS} =250V
			0.13	0.15		T _J =25°C, V _{CC} =10V, Id=6A
R _{DS(ON)}	Drain to Source ON Resistance		0.35		Ω	T _J =150°C, V _{CC} =10V, Id=6A (Note 4)
V_{SD}	Diode Forward Voltage		0.85		V	T _J =25°C, V _{CC} =10V, Id=6A
V _{HIN/LIN}	Logic "1" input voltage for HIN & "0" for LIN	2.2			V	
V _{HIN/LIN}	Logic "0" input voltage for HIN & "1" for LIN			0.8	V	
$V_{\text{CCUV+,}} \ V_{\text{BSUV+}}$	V _{CC} and V _{BS} Supply Under-Voltage, Positive Going Threshold	8	8.9	9.8	V	
V _{CCUV-} , V _{BSUV-}	V _{CC} and V _{BS} supply Under-Voltage, Negative Going Threshold	7.4	8.2	9.0	V	
V _{CCUVH} , V _{BSUVH}	V _{CC} and V _{BS} Supply Under-Voltage Lock-Out Hysteresis		0.7		V	
I _{QBS}	Quiescent V _{BS} Supply Current V _{IN} =0V		45	70	μΑ	
I _{QCC}	Quiescent V _{CC} Supply Current V _{IN} =0V		1100	3000	μΑ	
I _{HIN+}	Input Bias Current V _{IN} =4V		5	20	μA	
I _{LIN-}	Input Bias Current V _{IN} =0V		1	2	μA	
R _{BR}	Internal Bootstrap Equivalent Resistor Value		200		Ω	T _J =25°C

Note 4: Characterized, not tested at manufacturing

MOSFET Avalanche Characteristics

Symbol	Description	Min	Тур	Max	Units	Conditions
EAS	Single Pulse Avalanche Energy		430		mJ	T _J =25°C, L=3mH, VDD=150V, IAS=10A, TO- 220 package.



Dynamic Electrical Characteristics

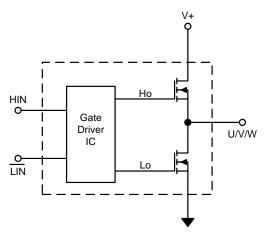
V_{BIAS} (V_{CC}, V_{BS})=15V, TJ=25°C, unless otherwise specified. Driver only timing unless otherwise specified.

Symbol	Description	Min	Тур	Max	Units	Conditions	
T _{ON}	Input to Output Propagation Turn- On Delay Time		0.8	1.3	μs	I _D =1mA, V ⁺ =50V	
T _{OFF}	Input to Output Propagation Turn- Off Delay Time		0.8	1.3	μs	Gate Driver; V _{LIN} =0 & V _{HIN} =5V with no external	
DT	Built-in Deadtime	0.9	1.3		μs	deadtime	
T _{FIL,IN}	Input Filter Time (HIN, LIN)		300		ns		

Thermal and Mechanical Characteristics

Symbol	Description	Min	Тур	Max	Units	Conditions
R _{th(J-B)}	Thermal resistance, junction to mounting pad, each MOSFET	-	1.3	-	°C/W	

Input-Output Logic Level Table



HIN	LIN	U,V,W
HI	HI	V+
LO	LO	0
HI	LO	**
LO	HI	*



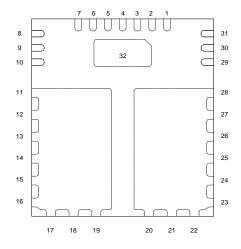
Qualification Information†

Qualification Level		Industrial ^{††} (per JEDEC JESD47)
Moisture Sensitivity Level		MSL3 ^{†††} (per IPC/JEDEC J-STD-020)
ESD	Machine Model	Class B (per JESD22-A115)
ESD	Human Body Model	Class 1C (per JESD22-A114)
RoHS Compliant		Yes

- † Qualification standards can be found at International Rectifier's web site http://www.irf.com/
- †† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.
- ††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.

Module Pin-Out Description

Pin	Name	Description
1, 4, 7, 32	COM	Low Side Gate Drive Return
2	VCC	15V Gate Drive Supply
3	HIN	Logic Input for High Side (Active High)
5	LIN	Logic Input for Low Side (Active Low)
6	DT	Dead time
8, 9, 10	V-	Low Side Source Connection
11 – 19	VS	Phase Output
20 – 28	V+	DC Bus
29 – 30	VS	Phase Output (-ve Bootstrap Cap Connection)
31	VB	High Side Floating Supply (+ve Bootstrap Cap Connection)



Exposed pad (Pin 32) has to be connected to COM for better electrical performance



Typical Application Connection IRSM808-204MH

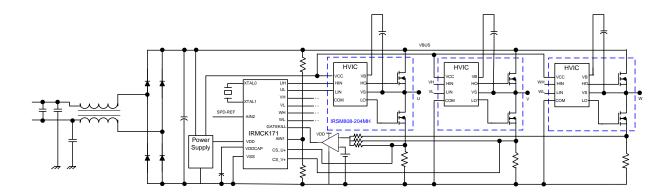
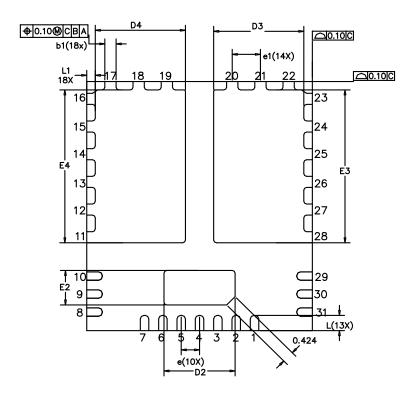


Figure 1: Typical Application Connection

- 1. Bus capacitors should be mounted as close to the module bus terminals as possible to reduce ringing and EMI problems. Additional high frequency ceramic capacitor mounted close to the module pins will further improve performance.
- 2. In order to provide a good decoupling between VCC-VSS and VB-VS terminals, the capacitors shown connected at these terminals should be located very close to the module pins. Additional high frequency capacitors, typically 0.1uF, are recommended.
- 3. Value of the boot-strap capacitors depends upon the switching frequency. Their selection should be made based on IR Design tip DT04-4 or application note AN-1044.



Package Outline IRSM808-204MH (Bottom View), 1 of 2

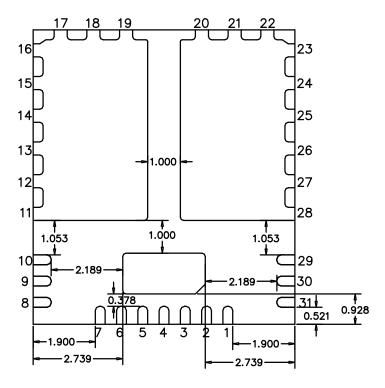


SYMBOL	DIMENSIONS IN MILLIMETER						
S							
	MIN.	NOM.	MAX.				
Α	0.800	0.900	1.000				
A1	0.000		0.050				
А3	0.2	203 REI	₹.				
b	0.250	0.300	0.350				
b1	0.350	0.350 0.400					
D	7.900	7.900 8.000					
Е	8.900	9.100					
D2	2.472	2.522	2.572				
E2	1.197	1.247	1.297				
D3	3.147	3.197	3.247				
E3	5.472	5.522	5.572				
D4	3.147	3.197	3.247				
E4	5.472	5.522	5.572				
е	0.0	0.650 BSC					
e1	1.000 BSC						
e2	1.4	403 BS	С				
е3	2.	318 BS	С				
L	0.500	0.550					
L1	0.253	0.303	0.353				

Dimensions in mm



Package Outline IRSM808-204MH (Bottom View), 2 of 2

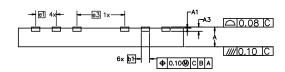


Dimensions in mm

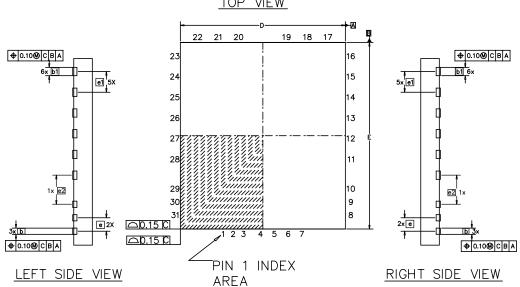


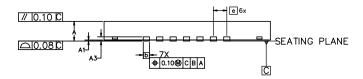
Package Outline IRSM808-204MH (Top & Side View)

BACK SIDE VIEW



TOP VIEW





FRONT SIDE VIEW

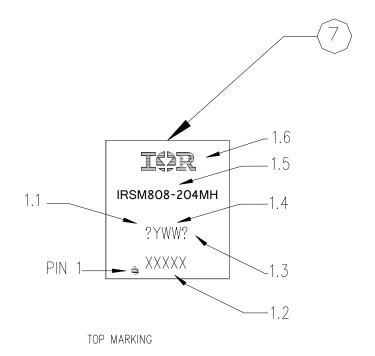
253 0.303 0.353

_	DIMENSIONS			E2	1.197	1.247	1.297	
SYMBOL	MII	IN MILLIMETER			D3	3.147	3.197	3.247
l io			MAX.		E3	5.472	5.522	5.572
	MIN.	NOM.			D4	3.147	3.197	3.247
A	0.800	0.900	1.000		F4	5.472		5.572
A1	0.000		0.050	1				
А3	0.1	203 REI	F.		е	0.650 BSC		
b	0.250	0.300	0.350		e1	1.000 BSC		
b1	0.350	0.400	0.450		e2	1.403 BSC		0
D	7.900	8.000	8.100		еЗ	2.318 BSC		
Е	8.900	9.000	9.100		L	0.500	0.550	0.600
D2	2.472	2.522	2.572		L1	0.253	0.303	0.353

Dimensions in mm



Top Marking



NOTES, MARKING:

- 1.1) SITE CODE: X 1.2) LAST 4 CHARACTER OF SPN/NANA CODE: XXXX
- 1.3) LEADFREE INDICATOR: P
- 1.4) DATE CODE: YWW
- 1.5) PART NUMBER: IRSM607-105MH
- 1.6) IR LOGO 1.7) MEDIUM:
- 1.7.1) TOP: LASER
- 1.7.2) BOTTOM: NONE



Data and Specifications are subject to change without notice IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 TAC Fax: (310) 252-7903

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